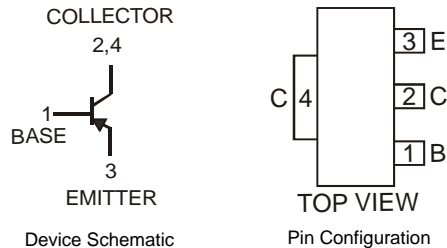


## Features

- Epitaxial Planar Die Construction
- Ideally Suited for Automated Assembly Processes
- Ideal for Medium Power Switching or Amplification Applications
- **Lead Free By Design/RoHS Compliant (Note 1)**
- **"Green" Device (Note 2)**

## Mechanical Data

- Case: SOT-223
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020D
- Terminals: Finish - Matte Tin annealed over Copper Leadframe (Lead Free Plating). Solderable per MIL-STD-202, Method 208
- Marking Information: See Page 4
- Ordering Information: See Page 4
- Weight: 0.115 grams (approximate)



Top View

Device Schematic

Pin Configuration

## Maximum Ratings @ $T_A = 25^\circ\text{C}$ unless otherwise specified

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	$V_{CBO}$	-180	V
Collector-Emitter Voltage	$V_{CEO}$	-140	V
Emitter-Base Voltage	$V_{EBO}$	-7	V
Continuous Collector Current	$I_C$	-4	A
Peak Pulse Current	$I_{CM}$	-10	A

## Thermal Characteristics

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 3) @ $T_A = 25^\circ\text{C}$	$P_D$	1	W
Thermal Resistance, Junction to Ambient Air (Note 3) @ $T_A = 25^\circ\text{C}$	$R_{\theta JA}$	125	$^\circ\text{C}/\text{W}$
Operating and Storage Temperature Range	$T_J, T_{STG}$	-55 to +150	$^\circ\text{C}$

- Notes:
1. No purposefully added lead.
  2. Diodes Inc.'s "Green" policy can be found on our website at [http://www.diodes.com/products/lead\\_free/index.php](http://www.diodes.com/products/lead_free/index.php).
  3. Device mounted on FR-4 PCB; pad layout as shown on page 4 or in Diodes Inc. suggested pad layout document AP02001, which can be found on our website at <http://www.diodes.com/datasheets/ap02001.pdf>.

**Electrical Characteristics** @ $T_A = 25^\circ\text{C}$  unless otherwise specified

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
<b>OFF CHARACTERISTICS (Note 4)</b>						
Collector-Base Breakdown Voltage	$V_{(BR)CBO}$	-180	-230	—	V	$I_C = -100\mu\text{A}, I_E = 0$
Collector-Emitter Breakdown Voltage	$V_{(BR)CEO}$	-140	-190	—	V	$I_C = -10\text{mA}, I_B = 0$
Emitter-Base Breakdown Voltage	$V_{(BR)EBO}$	-7	-8.5	—	V	$I_E = -100\mu\text{A}, I_C = 0$
Collector Cutoff Current	$I_{CBO}$	—	—	-20 -0.5	nA $\mu\text{A}$	$V_{CB} = -150\text{V}, I_E = 0$ $V_{CB} = -150\text{V}, I_E = 0,$ $T_A = 100^\circ\text{C}$
Emitter Cutoff Current	$I_{EBO}$	—	—	-10	nA	$V_{EB} = -6\text{V}, I_C = 0$
<b>ON CHARACTERISTICS (Note 4)</b>						
Collector-Emitter Saturation Voltage	$V_{CE(SAT)}$	—	-40 -50 -75 -175	-60 -80 -120 -360	mV	$I_C = -0.1\text{A}, I_B = -5\text{mA}$ $I_C = -0.5\text{A}, I_B = -50\text{mA}$ $I_C = -1\text{A}, I_B = -100\text{mA}$ $I_C = -3\text{A}, I_B = -300\text{mA}$
Base-Emitter Saturation Voltage	$V_{BE(SAT)}$	—	-910	-1040	mV	$I_C = -3\text{A}, I_B = -300\text{mA}$
Base-Emitter Turn-On Voltage	$V_{BE(ON)}$	—	-810	-930	mV	$I_C = -3\text{A}, V_{CE} = -5\text{V}$
DC Current Gain	$h_{FE}$	100 100 45 —	— — — 12	— — 300 —	—	$I_C = -10\text{mA}, V_{CE} = -5\text{V}$ $I_C = -1\text{A}, V_{CE} = -5\text{V}$ $I_C = -3\text{A}, V_{CE} = -5\text{V}$ $I_C = -10\text{A}, V_{CE} = -5\text{V}$
<b>SMALL SIGNAL CHARACTERISTICS</b>						
Current Gain-Bandwidth Product	$f_T$	—	150	—	MHz	$I_C = -100\text{mA}, V_{CE} = -10\text{V},$ $f = 100\text{MHz}$
Output Capacitance	$C_{obo}$	—	55	—	pF	$V_{CB} = -10\text{V}, f = 1\text{MHz}$
<b>SWITCHING CHARACTERISTICS</b>						
Switching Times	$t_{on}$ $t_{off}$	— —	85 430	— —	ns	$I_C = -1\text{A}, I_{B1} = -100\text{mA}$ $I_{B2} = 100\text{mA}, V_{CC} = -50\text{V}$

Notes: 4. Measured under pulsed conditions. Pulse width = 300 $\mu\text{s}$ . Duty cycle  $\leq 2\%$

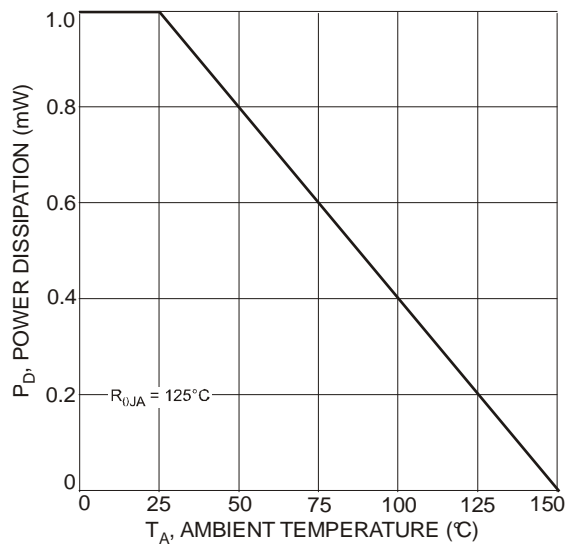


Fig. 1 Power Dissipation vs. Ambient Temperature (Note 3)

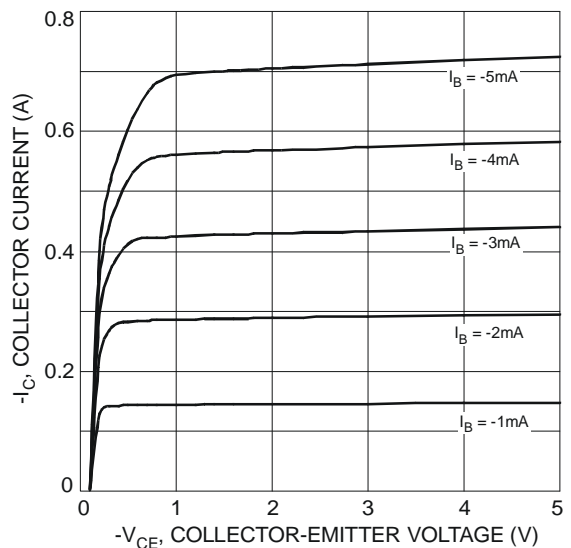


Fig. 2 Typical Collector Current vs. Collector-Emitter Voltage

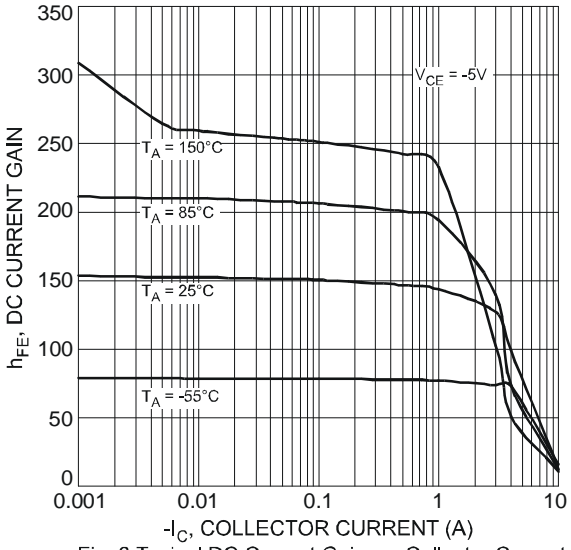


Fig. 3 Typical DC Current Gain vs. Collector Current

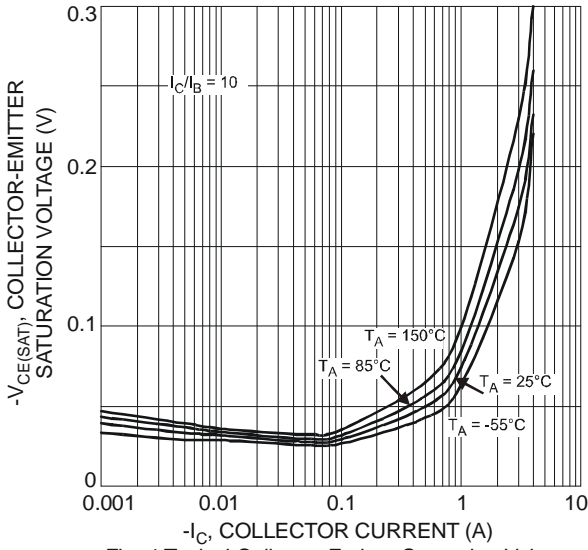


Fig. 4 Typical Collector-Emitter Saturation Voltage vs. Collector Current

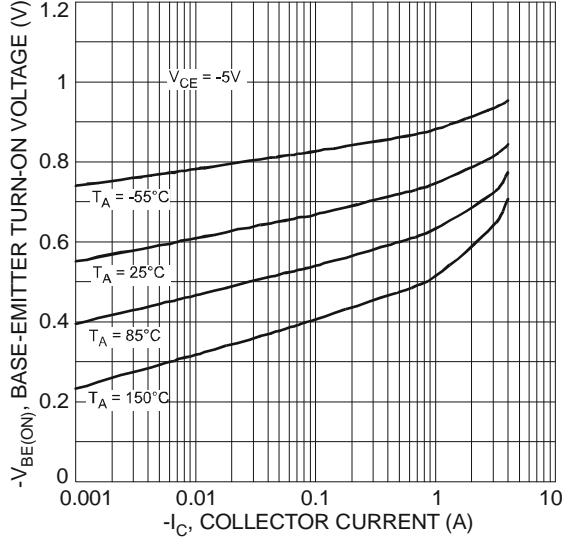


Fig. 5 Typical Base-Emitter Turn-On Voltage vs. Collector Current

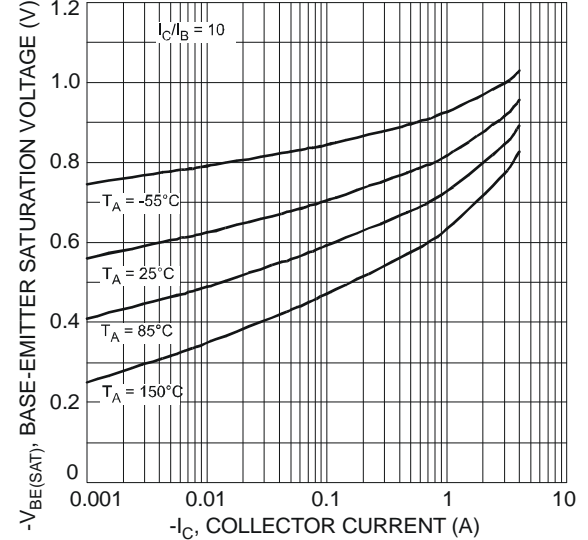


Fig. 6 Typical Base-Emitter Saturation Voltage vs. Collector Current

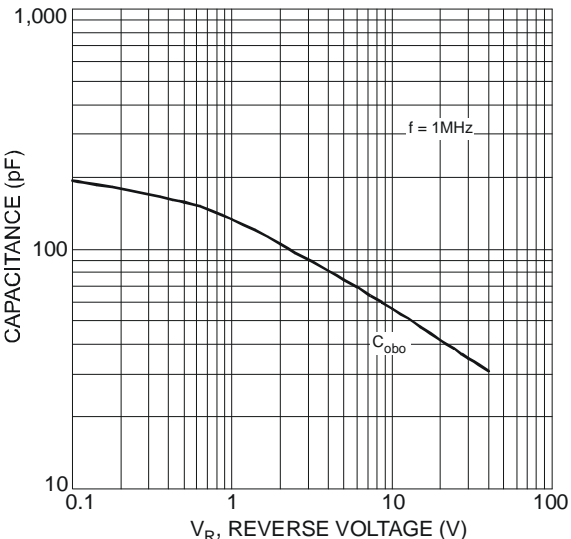


Fig. 7 Typical Capacitance Characteristics

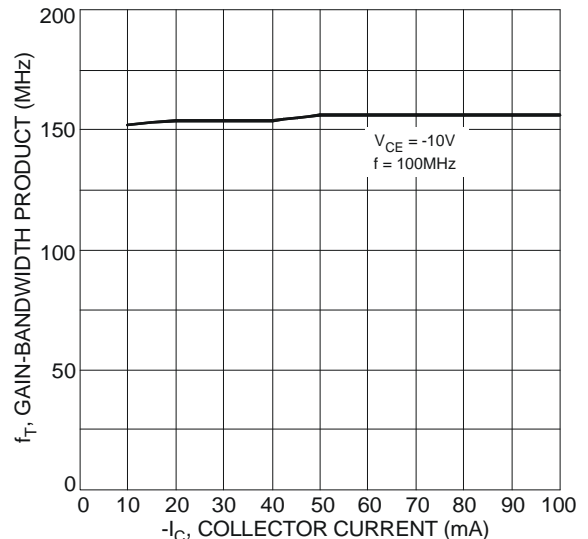


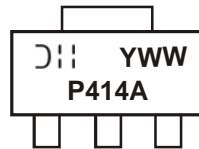
Fig. 8 Typical Gain-Bandwidth Product vs. Collector Current

**Ordering Information** (Note 5)

Part Number	Case	Packaging
DPLS4140E-13	SOT-223	2500/Tape & Reel

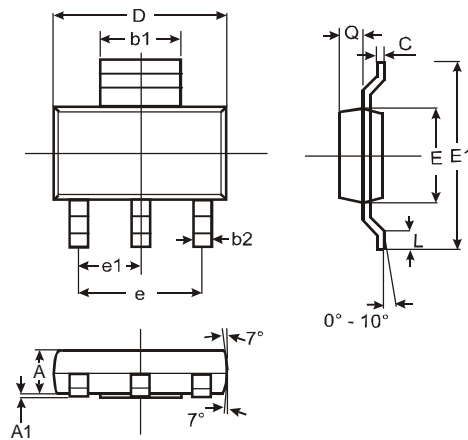
Notes: 5. For packaging details, go to our website at <http://www.diodes.com/datasheets/ap02007.pdf>.

**Marking Information**



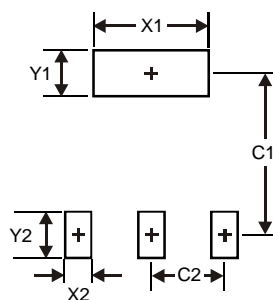
P414A = Product Type Marking Code  
 YWW = Date Code Marking  
 Y = Last digit of year (ex: 8 = 2008)  
 WW = Week code 01 - 52

**Package Outline Dimensions**



SOT-223			
Dim	Min	Max	Typ
A	1.55	1.65	1.60
A1	0.010	0.15	0.05
b1	2.90	3.10	3.00
b2	0.60	0.80	0.70
C	0.20	0.30	0.25
D	6.45	6.55	6.50
E	3.45	3.55	3.50
E1	6.90	7.10	7.00
e	—	—	4.60
e1	—	—	2.30
L	0.85	1.05	0.95
Q	0.84	0.94	0.89
All Dimensions in mm			

**Suggested Pad Layout**



Dimensions	Value (in mm)
X1	3.3
X2	1.2
Y1	1.6
Y2	1.6
C1	6.4
C2	2.3

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